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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China











DMP3099L

#### P-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
-30V	$65m\Omega$ @ $V_{GS}$ = -10 $V$	-3.8A
-30 V	$99m\Omega$ @ $V_{GS}$ = -4.5 $V$	-3.0A

### **Description**

This MOSFET has been designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

### **Applications**

- Backlighting
- Power Management Functions
- DC-DC Converters

#### **Features and Benefits**

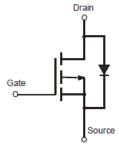
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

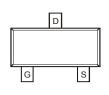
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe.
  Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)







**Equivalent Circuit** 



Top View Pin Configuration

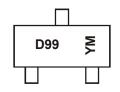
### Ordering Information (Note 4)

Part Number	Compliance	Case	Packaging
DMP3099L-7	Standard	SOT23	3000/Tape & Reel
DMP3099L-13	Standard	SOT23	10000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

# **Marking Information**



D99= Product Type Marking Code

YM = Date Code Marking

Y = Year (ex: V = 2008)

M = Month (ex: 9 = September)

Date Code Key

Year	2008		2009	2010		2011	2012		2013	2014		2015
Code	V		W	Х		Υ	Z		Α	В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Au	g Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteris		Symbol	Value	Units	
Drain-Source Voltage		$V_{DSS}$	-30	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V	
Drain Current (Note 5) $V_{GS} = -10V$ Steady $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$			I <sub>D</sub>	-3.8 -2.9	Α
Pulsed Drain Current (Note 6)		I <sub>DM</sub>	-11	Α	

# **Thermal Characteristics**

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	$P_{D}$	1.08	W
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 5)	$R_{\theta JA}$	115	°C/W
Operating and Storage Temperature Range	$T_{J_1}T_{STG}$	-55 to +150	°C

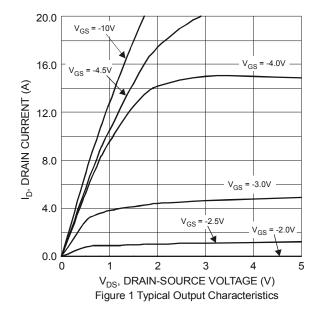
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

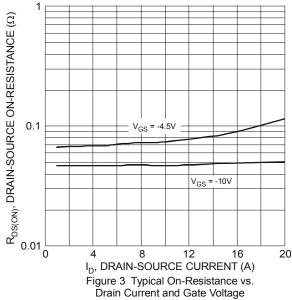
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	-800	nA	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	$I_{GSS}$	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	$V_{GS(th)}$	-1.0	_	-2.1	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain Source On Begintance				65	mΩ	$V_{GS} = -10V, I_D = -3.8A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		_	99	11122	$V_{GS} = -4.5V$ , $I_D = -3.0A$	
Forward Transfer Admittance	Y <sub>fs</sub>	_	3.6	_	S	$V_{DS} = -5V, I_{D} = -2.7A$	
Diode Forward Voltage (Note 6)	$V_{SD}$	_	_	-1.26	V	$V_{GS} = 0V, I_{S} = -2.7A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	_	563	_	pF	\/ - 25\/ \/ - 0\/	
Output Capacitance	Coss	_	48	_	pF	$V_{DS} = -25V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	$C_{rss}$	_	41	_	pF		
Gate Resistance	$R_G$	_	10.3	_	Ω	$V_{GS} = 0V V_{DS} = 0V, f = 1MHz$	
SWITCHING CHARACTERISTICS (Note 8)							
Total Gate Charge	$Q_g$	_	5.2			$V_{DS} = -15V$ , $V_{GS} = -4.5V$ , $I_{D} = -3.8A$	
Total Guic Glarge	₩g		11	_	nC		
Gate-Source Charge	Q <sub>gs</sub>	_	1.7	_		$V_{DS} = -15V, V_{GS} = -10V,$ $I_{D} = -3.8A$	
Gate-Drain Charge	$Q_{gd}$	_	1.9	_			
Turn-On Delay Time	t <sub>d(on)</sub>	_	4.8	_			
Rise Time	t <sub>r</sub>	_	5.0	_	no	$V_{DS} = -15V, V_{GS} = -10V,$	
Turn-Off Delay Time	$t_{d(off)}$	_	31	_	ns	$I_D = -1A, R_G = 6.0\Omega$	
Fall Time	t <sub>f</sub>	_	15	_			

Notes:

- 5. Device mounted on FR-4 PCB on 2 oz., 0.5 in. $^2$  copper pads and t  $\leq$ 5 sec. 6. Pulse width  $\leq$ 10 $\mu$ S, Duty Cycle  $\leq$ 1%.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.







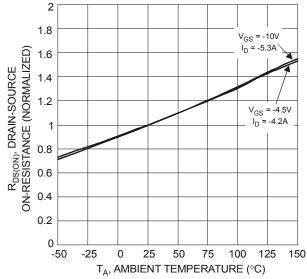
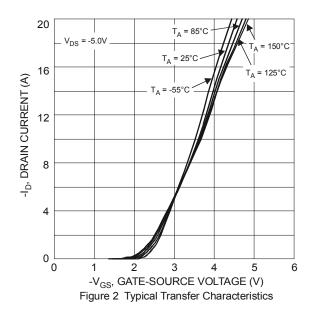
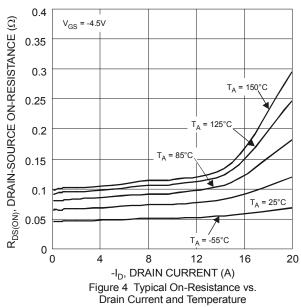


Figure 5 On-Resistance Variation with Temperature





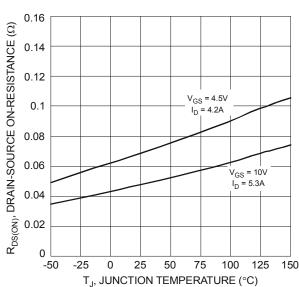


Figure 6 On-Resistance Variation with Temperature



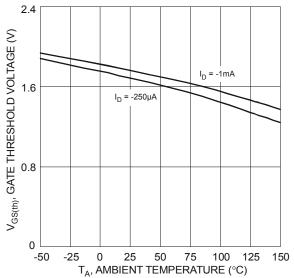
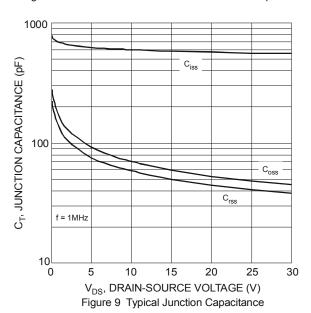
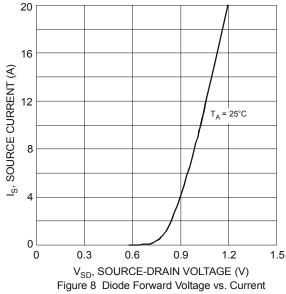
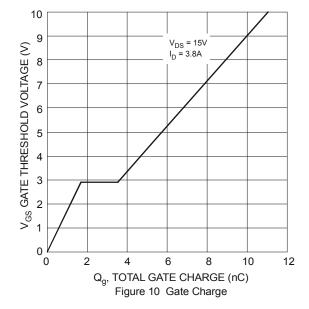


Figure 7 Gate Threshold Variation vs. Ambient Temperature



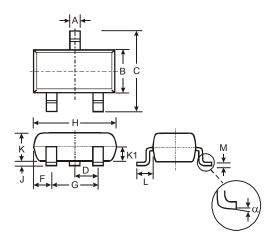






# **Package Outline Dimensions**

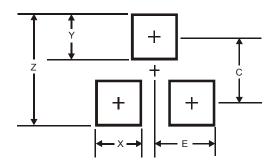
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23								
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.903	1.10	1.00					
K1	-	-	0.400					
L	0.45	0.61	0.55					
M	0.085	0.18	0.11					
α	0°	8°	-					
All Dimensions in mm								

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Υ	0.9
С	2.0
E	1.35



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